LM614x 17MHz Rail-to-Rail Input-Output Operational Amplifiers

1 Features

At V_S = 5V. Typ Unless Noted.

- Rail-to-rail Input CMVR −0.25V to 5.25V
- Rail-to-Rail Output
- Wide Gain-Bandwidth: 17MHz at 50kHz (typ)
- Slew Rate: 30V/µs
- Low Supply Current 650µA/Amplifier
- Wide Supply Range 2.7V to 24V
- CMRR 107dB
- Gain 108dB with R_L = 10k
- PSRR 87dB

2 Applications

- Battery Operated Instrumentation
- Depth Sounders/Fish Finders
- Barcode Scanners
- Wireless Communications
- Rail-to-Rail in-out Instrumentation Amps

3 Description

Using patent pending new circuit topologies, the LM6142/LM6144 provides new levels of performance in applications where low voltage supplies or power limitations previously made compromise necessary. Operating on supplies of 2.7V to over 24V, the LM6142/LM6144 is an excellent choice for battery operated systems, portable instrumentation and others.

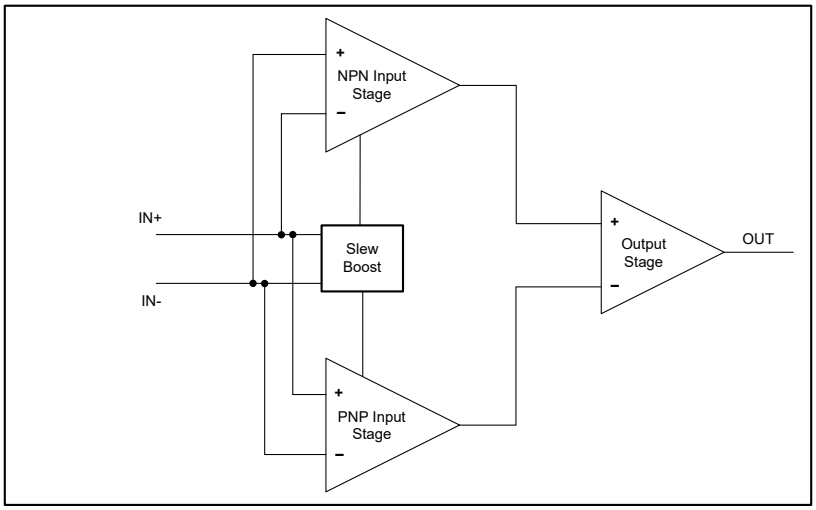
The greater than rail-to-rail input voltage range eliminates concern over exceeding the common-mode voltage range. The rail-to-rail output swing provides the maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.

High gain-bandwidth with 650µA/Amplifier supply current opens new battery powered applications where previous higher power consumption reduced battery life to unacceptable levels. The ability to drive large capacitive loads without oscillating functionally removes this common problem.

Device Information

PART NUMBER	CHANNEL COUNT	PACKAGE(1)	BODY SIZE
LM6142	Dual	D (SOIC, 8)	4.90mm × 3.91mm
		P (PDIP, 8)	9.81mm × 6.35mm
LM6144	Quad	D (SOIC, 14)	8.65mm × 3.91mm
		NFF (PDIP, 14)	19.177mm × 6.35mm

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Functional Block Diagram

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4 Connection Diagrams

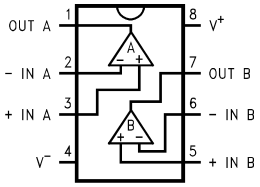


Figure 4-1. 8-Pin CDIP
Top View

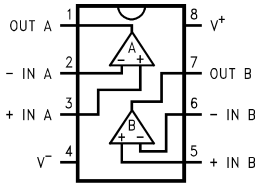


Figure 4-2. 8-Pin PDIP/SOIC
Top View

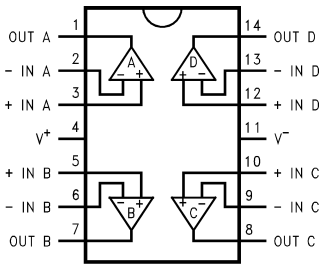


Figure 4-3. 14-Pin PDIP/SOIC
Top View

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5 Specifications

5.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage, V_S = (V+) – (V–)		0	33	V
Signal input pins	Common-mode voltage(3)	(V–) – 0.5	(V+) + 0.5	V
	Differential voltage(4)		±15	V
	Current(3)		±10	mA
Output short-circuit(2)		Continuous		
Operating ambient temperature, T_A		–55	150	°C
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Operating the device beyond the ratings listed under *Absolute Maximum Ratings* will cause permanent damage to the device. These are stress ratings only, based on process and design limitations, and this device has not been designed to function outside the conditions indicated under *Recommended Operating Conditions*. Exposure to any condition outside *Recommended Operating Conditions* for extended periods, including absolute-maximum-rated conditions, may affect device reliability and performance.
(2) Short-circuit to ground, one amplifier per package. Extended short-circuit current, especially with higher supply voltage, can cause excessive heating and eventual destruction.
(3) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
(4) Input pins are connected by back-to-back diodes for input protection. If the differential input voltage may exceed 0.5 V, limit the input current to 10mA or less.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±4000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002(2)	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_S	Supply voltage, (V+) – (V–)	2.7	32	V
T_A	Specified temperature	–40	85	°C

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5.4 Thermal Information LM6142

THERMAL METRIC[1]		LM6142		UNIT
		D (SOIC)[1]	P (PDIP)[1]	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	127.10	84.45	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	63.27	58.07	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	71.20	50.90	°C/W
ψ_{JT}	Junction-to-top characterization parameter	13.91	30.43	°C/W
ψ_{JB}	Junction-to-board characterization parameter	70.54	50.44	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

5.5 Thermal Information LM6144

THERMAL METRIC[1]		LM6144		Unit
		D (SOIC)[1]	NFF (PDIP)[1]	
		14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	82.48	81	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	38.77	N/A	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	37.86	N/A	°C/W
ψ_{JT}	Junction-to-top characterization parameter	8.66	N/A	°C/W
ψ_{JB}	Junction-to-board characterization parameter	37.51	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

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5.6 Electrical Characteristics: V_S = 5V

For V^+ = 5.0V, V^- = 0V, R_L > 1MΩ connected to V_S / 2, V_{CM} = V^+ / 2, and V_O = V^+ / 2, at T_A = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage	LM6142AI, LM6144AI			0.3	1	mV
			T_A = –40°C to 85°C			2.2	
		LM6142BI, LM6144BI			0.3	2.5	
			T_A = –40°C to 85°C			3.3	
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to 85°C			3		µV/°C
PSRR	Input offset voltage versus power supply	2.5V ≤ $\|V_S\|$ ≤ 12V, LM6132AI, LM6134AI		78	82		dB
			T_A = –40°C to 85°C	75			
		2.5V ≤ $\|V_S\|$ ≤ 12V, LM6132BI, LM6134BI		78	82		
			T_A = –40°C to 85°C	75			
	Amp-to-amp isolation				130		dB
INPUT BIAS CURRENT							
I_B	Input bias current	LM6142AI, LM6144AI			170	250	nA
		LM6142BI, LM6144BI			170	300	
		0V ≤ V_{CM} ≤ 5V, LM6142AI, LM6144AI			180	280	
			T_A = –40°C to 85°C			526	
		0V ≤ V_{CM} ≤ 5V, LM6142BI, LM6144BI			180		
			T_A = –40°C to 85°C			526	
I_{OS}	Input offset current	LM6142AI, LM6144AI			3	30	nA
			T_A = –40°C to 85°C			80	
		LM6142BI, LM6144BI			3	30	
			T_A = –40°C to 85°C			80	
INPUT VOLTAGE							
V_{CM}	Common-mode input voltage range			– 0.25		5.25	V
		T_A = –40°C to 85°C		0		5	V
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤ 4V, LM6142AI, LM6144AI		84	107		dB
			T_A = –40°C to 85°C	78			
		0V ≤ V_{CM} ≤ 4V, LM6142BI, LM6144BI		84	107		
			T_A = –40°C to 85°C	78			
		0V ≤ V_{CM} ≤ 5V, LM6142AI, LM6144AI		66	82		
			T_A = –40°C to 85°C	64	79		
		0V ≤ V_{CM} ≤ 5V, LM6142BI, LM6144BI		66	82		
			T_A = –40°C to 85°C	64	79		
INPUT IMPEDANCE							
R_{IN}	Common-mode input resistance				126		MΩ
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	R_L = 10kΩ, LM6142AI, LM6144AI		100	270		V/mV
			T_A = –40°C to 85°C	33	70		
		R_L = 10kΩ, LM6142BI, LM6144BI		80	270		
			T_A = –40°C to 85°C	25	70		
NOISE							
e_N	Input voltage noise density	f = 1kHz			16		nV/√Hz
i_N	Input current noise density	f = 1kHz			0.22		pA/√Hz
FREQUENCY RESPONSE							
GBW	Gain-bandwidth product	f = 50kHz		10	17		MHz
			T_A = –40°C to 85°C	6			

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For V^+ = 5.0V, V^- = 0V, R_L > 1MΩ connected to V_S / 2, V_{CM} = V^+ / 2, and V_O = V^+ / 2, at T_A = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR	Slew rate	V_S = 12V, V_{STEP} = 8V, R_S > 1kΩ	LM6142AI, LM6144AI	15	25		V/µs
			LM6142AI, LM6144AI, T_A = –40°C to 85°C	13			
			LM6142AI, LM6144AI	13	25		
			LM6142AI, LM6144AI, T_A = –40°C to 85°C	11			
PM	Phase margin				38		°
THD+N	Total harmonic distortion + noise	f = 10kHz, R_L = 10kΩ			0.003		%
OUTPUT							
V_O	Voltage output swing	R_L = 100kΩ, From positive rail			30	40	mV
			T_A = –40°C to 85°C			70	
		R_L = 100kΩ, From negative rail			45	50	
			T_A = –40°C to 85°C			60	
		R_L = 10kΩ, From positive rail			40		
		R_L = 10kΩ, From negative rail			50		
		R_L = 2kΩ, From positive rail			100	140	
			T_A = –40°C to 85°C			200	
		R_L = 2kΩ, From negative rail			60	100	
			T_A = –40°C to 85°C			133	
I_{SC}	Short-circuit current	Sourcing, LM6142A		10	13		mA
			T_A = –40°C to 85°C	4.9		35	
		Sourcing, LM6142B		8	13		
			T_A = –40°C to 85°C	4		35	
		Sinking, LM6142A		10	24		
			T_A = –40°C to 85°C	5.3		35	
		Sinking, LM6142B		10	24		
			T_A = –40°C to 85°C	5.3		35	
		Sourcing, LM6144A		6	8		
			T_A = –40°C to 85°C	3		35	
		Sourcing, LM6144B		6	8		
			T_A = –40°C to 85°C	3		25	
		Sinking, LM6144A		8	22		
			T_A = –40°C to 85°C	4		25	
		Sinking, LM6144B		8	22		
			T_A = –40°C to 85°C	4		35	
POWER SUPPLY							
I_Q	Quiescent current per amplifier	LM6142AI, LM6144AI			650	800	µA
			T_A = –40°C to 85°C			880	
		LM6142BI, LM6144BI			650	800	µA
			T_A = –40°C to 85°C			880	µA

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5.7 Electrical Characteristics: V_S = 2.7V

For V^+ = 2.7V, V^- = 0V, R_L > 1MΩ connected to V_S / 2, V_{CM} = V^+ / 2, and V_O = V^+ / 2, at T_A = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage	LM6142AI, LM6144AI			0.4	1.8	mV
			T_A = –40°C to 85°C			4.3	
		LM6142BI, LM6144BI			0.4	2.5	
			T_A = –40°C to 85°C			5	
PSRR	Input offset voltage versus power supply	3V ≤ V^+ ≤ 5V			79		dB
INPUT BIAS CURRENT							
I_B	Input bias current	LM6142AI, LM6144AI			150	250	nA
			T_A = –40°C to 85°C			526	
		LM6142BI, LM6144BI			150	300	
			T_A = –40°C to 85°C			526	
I_{OS}	Input offset current	LM6142AI, LM6144AI			4	30	nA
			T_A = –40°C to 85°C			80	
		LM6142BI, LM6144BI			4	30	
			T_A = –40°C to 85°C			80	
INPUT VOLTAGE							
V_{CM}	Common-mode input voltage range			0		2.7	V
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤ 1.8V			90		dB
		0V ≤ V_{CM} ≤ 2.7V			76		
INPUT IMPEDANCE							
R_{IN}	Common-mode input resistance				128		MΩ
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	R_L = 10kΩ			55		V/mV
NOISE							
FREQUENCY RESPONSE							
GBW	Gain-bandwidth product	f = 50kHz			9		MHz
PM	Phase margin				36		°
GM	Gain margin				6		dB
OUTPUT							
V_O	Voltage output swing	R_L = 100kΩ, From positive rail			30	75	mV
			T_A = –40°C to 85°C			450	
		R_L = 100kΩ, From negative rail			19	80	
			T_A = –40°C to 85°C			112	
POWER SUPPLY							
I_Q	Quiescent current per amplifier	LM6142AI, LM6144AI			510	800	µA
			T_A = –40°C to 85°C			880	
		LM6142BI, LM6144BI			510	800	µA
			T_A = –40°C to 85°C			880	µA

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5.8 Electrical Characteristics: V_S = 24V

For V^+ = 24V, V^- = 0V, R_L > 1MΩ connected to V_S / 2, V_{CM} = V^+ / 2, and V_O = V^+ / 2, at T_A = 25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage	LM6142AI, LM6144AI			1.3	2	mV
			T_A = –40°C to 85°C			4.8	
		LM6142BI, LM6144BI			1.3	3.8	
			T_A = –40°C to 85°C			4.8	
PSRR	Input offset voltage versus power supply	0V ≤ V_S ≤ 24V			87		dB
INPUT BIAS CURRENT							
I_B	Input bias current				174		nA
I_{OS}	Input offset current				5		nA
INPUT VOLTAGE							
V_{CM}	Common-mode input voltage range			0		24	V
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤ 23V			114		dB
		0V ≤ V_{CM} ≤ 24V			100		
INPUT IMPEDANCE							
R_{IN}	Common-mode input resistance				288		MΩ
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	R_L = 10kΩ			500		V/mV
NOISE							
FREQUENCY RESPONSE							
GBW	Gain-bandwidth product	f = 50kHz			18		MHz
OUTPUT							
V_O	Voltage output swing	R_L = 10kΩ, From positive rail			150	190	mV
			T_A = –40°C to 85°C			380	
		R_L = 10kΩ, From negative rail			70	150	
			T_A = –40°C to 85°C			185	
POWER SUPPLY							
I_Q	Quiescent current per amplifier	LM6142AI, LM6144AI			750	1100	µA
			T_A = –40°C to 85°C			1150	
		LM6142BI, LM6144BI			750	1100	µA
			T_A = –40°C to 85°C			1150	µA

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5.9 Typical Characteristics

at T_A = 25°C and R_L = 10 kΩ (unless otherwise noted)

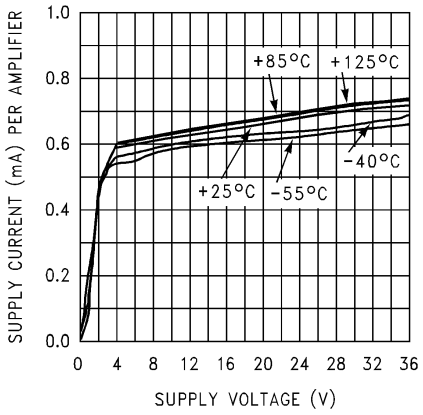


Figure 5-1. Supply Current vs Supply Voltage

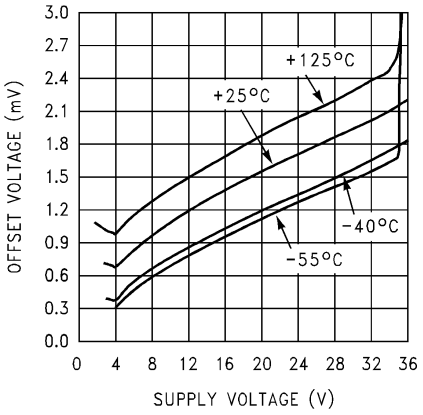


Figure 5-2. Offset Voltage vs Supply Voltage

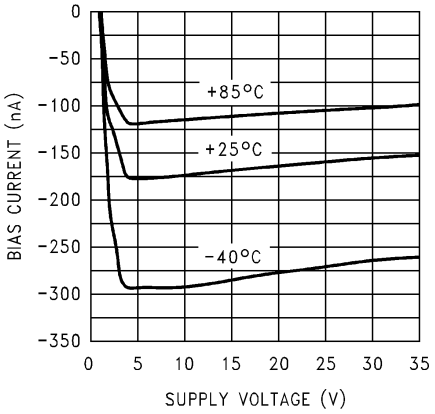


Figure 5-3. Bias Current vs Supply Voltage

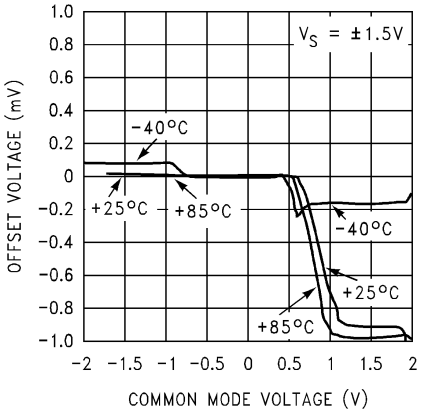


Figure 5-4. Offset Voltage vs V_{CM}

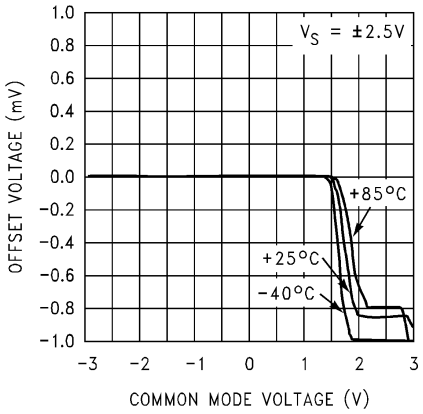


Figure 5-5. Offset Voltage vs V_{CM}

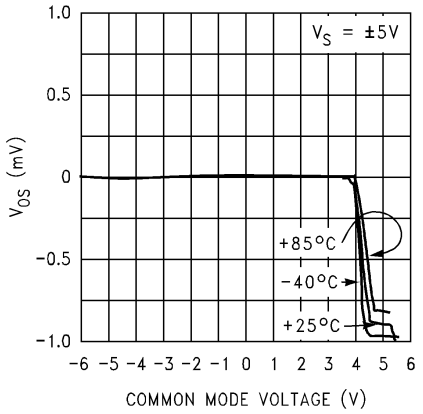


Figure 5-6. Offset Voltage vs V_{CM}

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5.9 Typical Characteristics (continued)

at T_A = 25°C and R_L = 10 kΩ (unless otherwise noted)

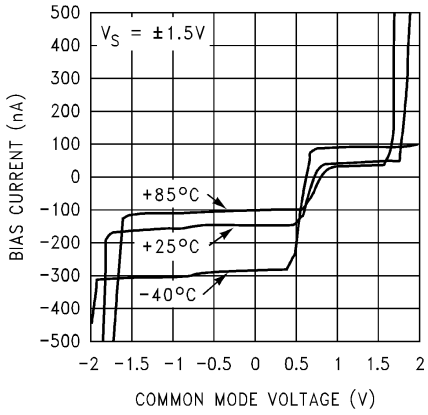


Figure 5-7. Bias Current vs V_{CM}

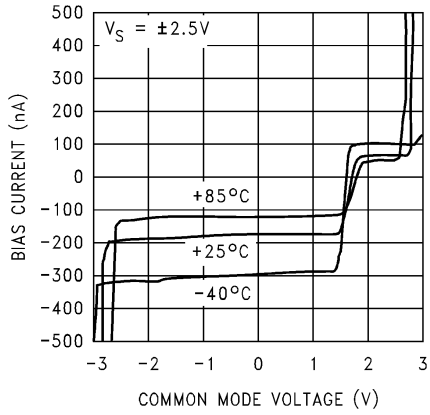


Figure 5-8. Bias Current vs V_{CM}

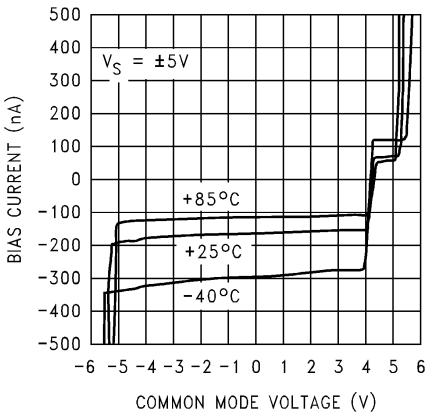


Figure 5-9. Bias Current vs V_{CM}

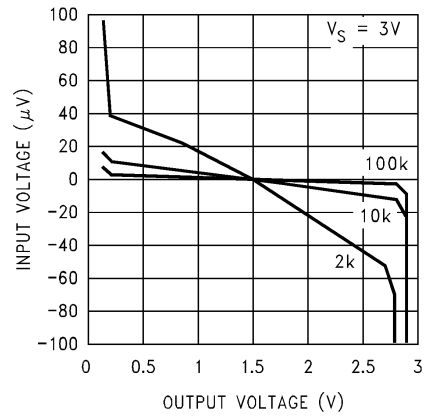


Figure 5-10. Open-Loop Transfer Function

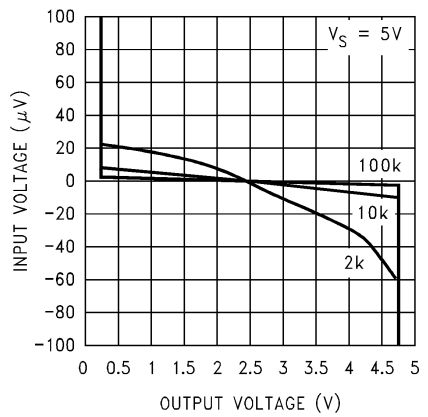


Figure 5-11. Open-Loop Transfer Function

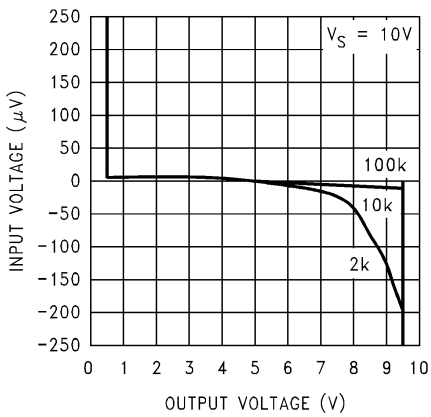


Figure 5-12. Open-Loop Transfer Function

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5.9 Typical Characteristics (continued)

at T_A = 25°C and R_L = 10 kΩ (unless otherwise noted)

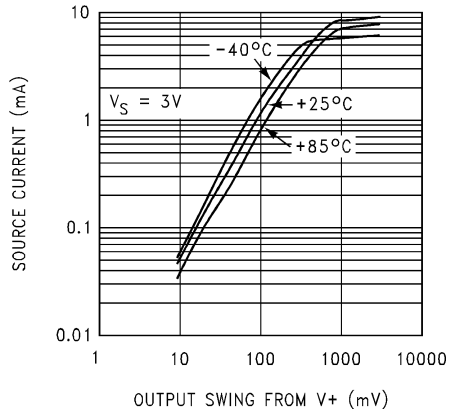


Figure 5-13. Output Voltage vs Source Current

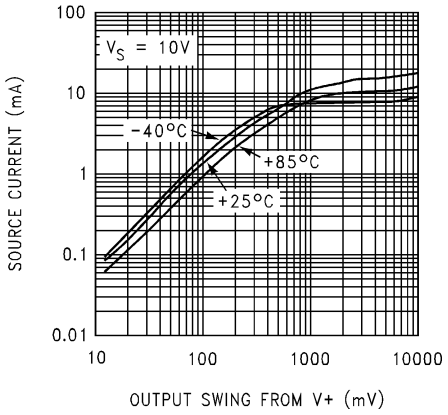


Figure 5-14. Output Voltage vs Source Current

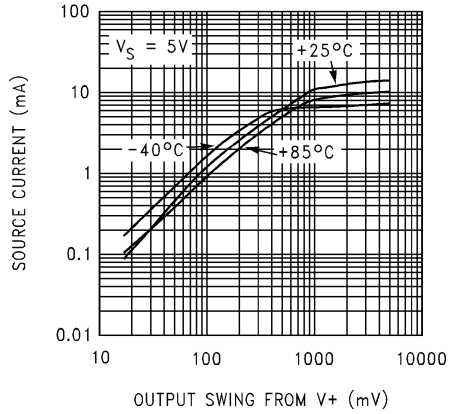


Figure 5-15. Output Voltage vs Source Current

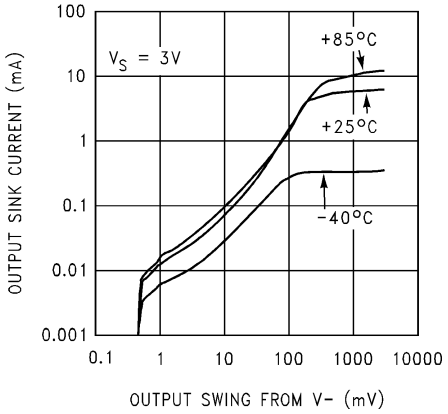


Figure 5-16. Output Voltage vs Sink Current

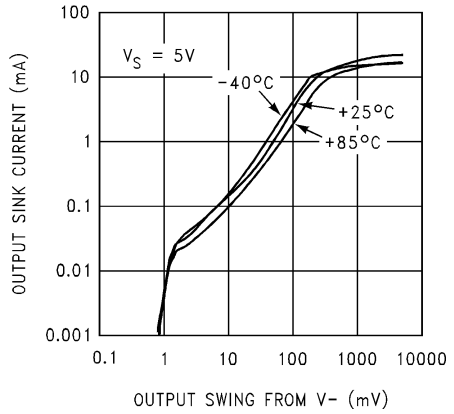


Figure 5-17. Output Voltage vs Sink Current

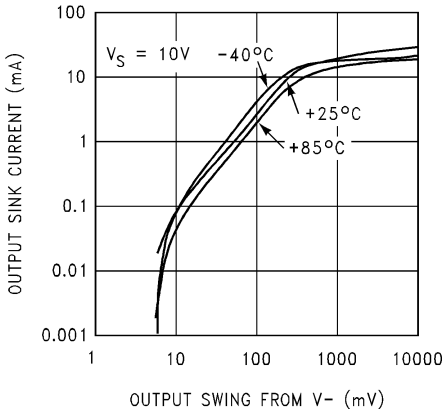


Figure 5-18. Output Voltage vs Sink Current

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5.9 Typical Characteristics (continued)

at T_A = 25°C and R_L = 10 kΩ (unless otherwise noted)

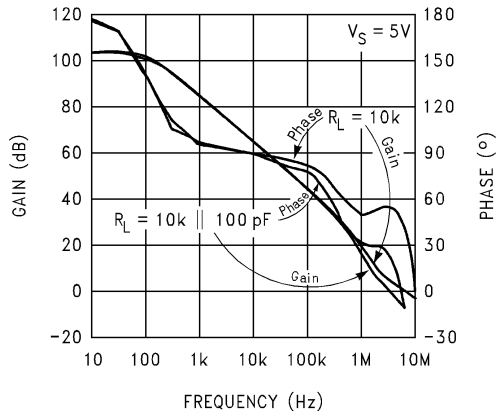


Figure 5-19. Gain and Phase vs Load

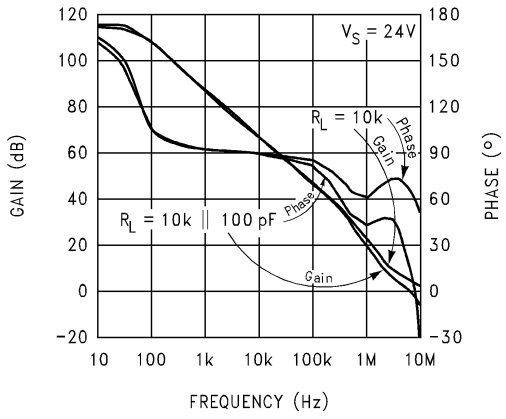


Figure 5-20. Gain and Phase vs Load

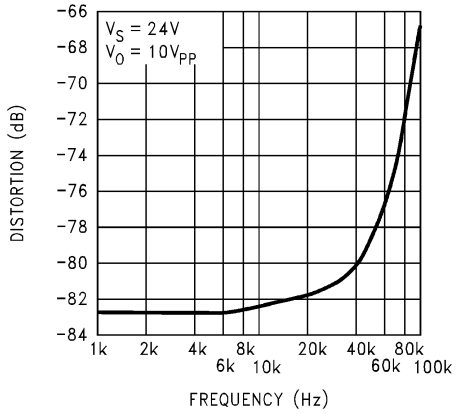


Figure 5-21. Distortion + Noise vs Frequency

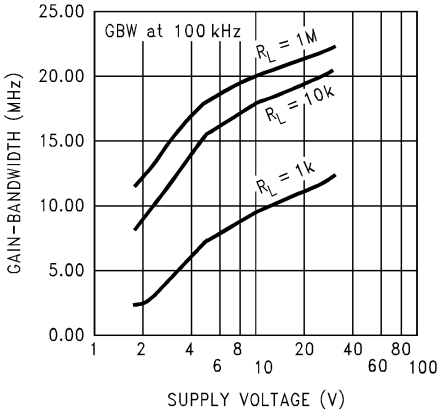


Figure 5-22. GBW vs Supply

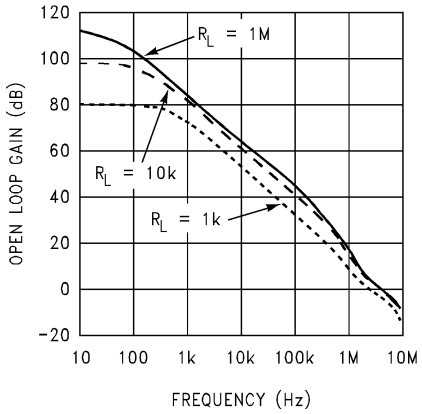


Figure 5-23. Open Loop Gain vs Load, 3V Supply, Old Die

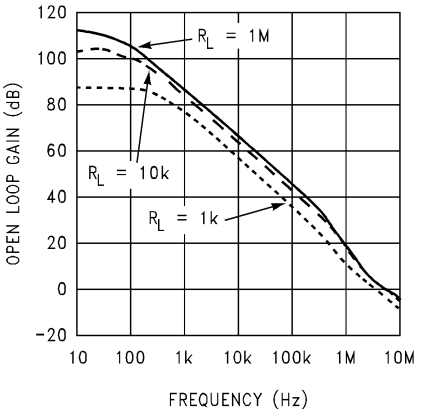


Figure 5-24. Open Loop Gain vs Load, 5V Supply, Old Die

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5.9 Typical Characteristics (continued)

at T_A = 25°C and R_L = 10 kΩ (unless otherwise noted)

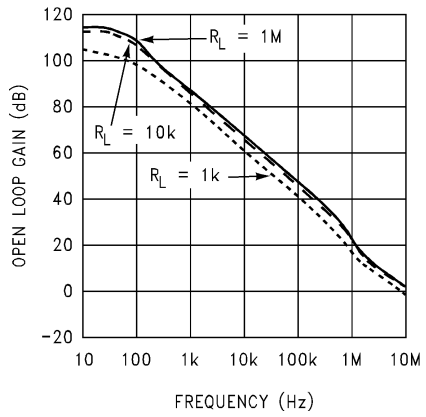


Figure 5-25. Open Loop Gain vs Load, 24V Supply, Old Die

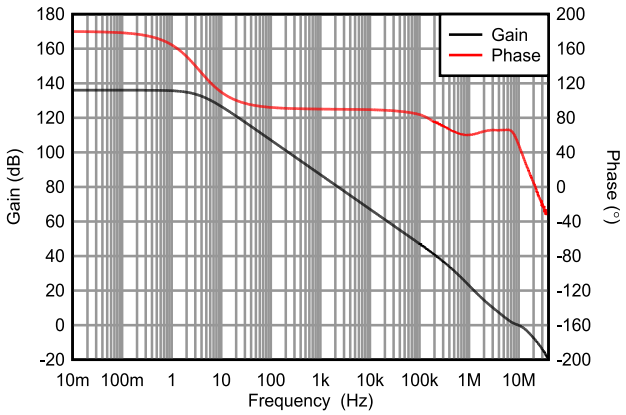


Figure 5-26. Open Loop Gain vs Load, 5V Supply, New Die

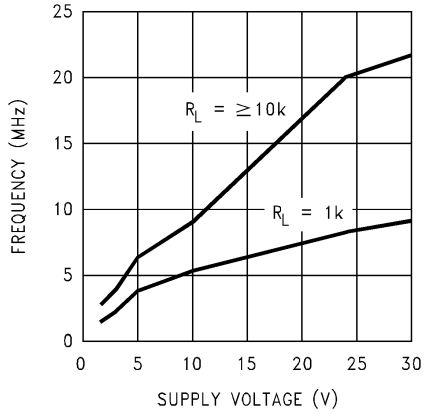


Figure 5-27. Unity Gain Frequency vs V_S

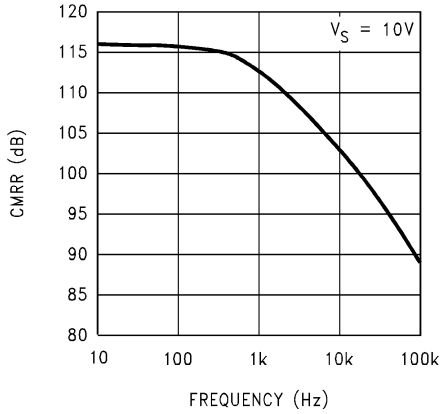


Figure 5-28. CMRR vs Frequency, Old Die

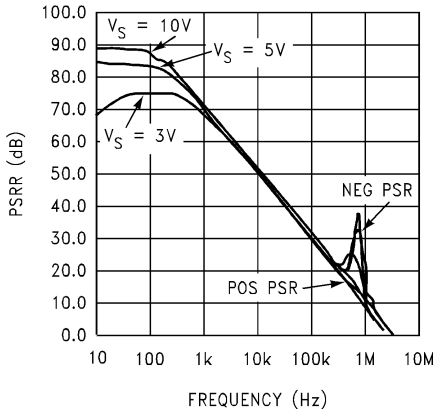


Figure 5-29. PSRR vs Frequency, Old Die

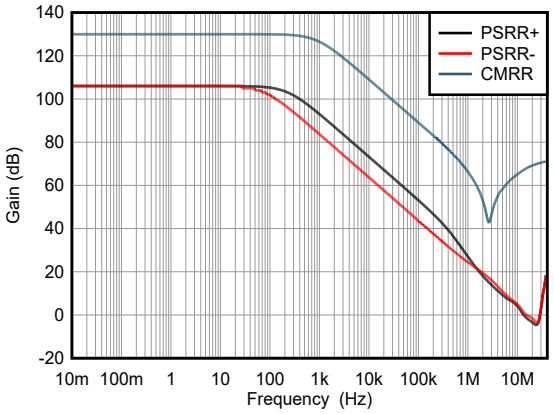


Figure 5-30. CMRR and PSRR vs Frequency, New Die

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5.9 Typical Characteristics (continued)

at T_A = 25°C and R_L = 10 kΩ (unless otherwise noted)

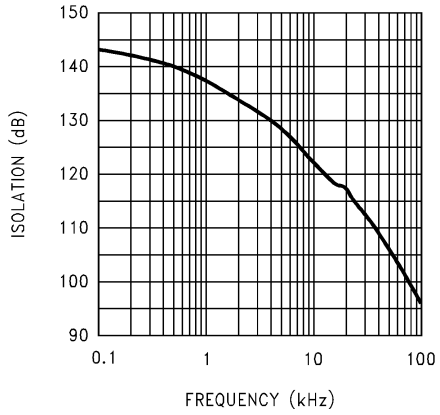


Figure 5-31. Crosstalk vs Frequency

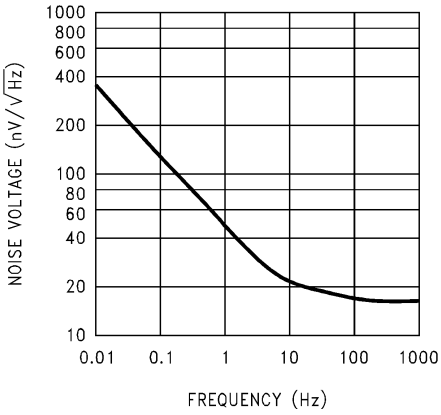


Figure 5-32. Noise Voltage vs Frequency

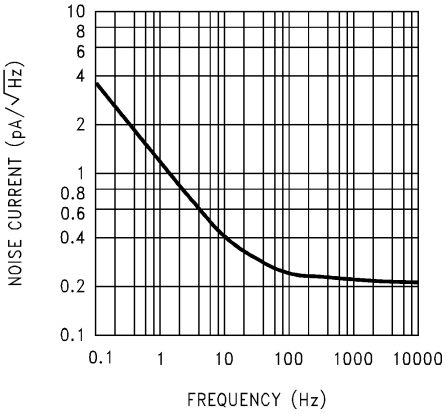


Figure 5-33. Noise Current vs Frequency

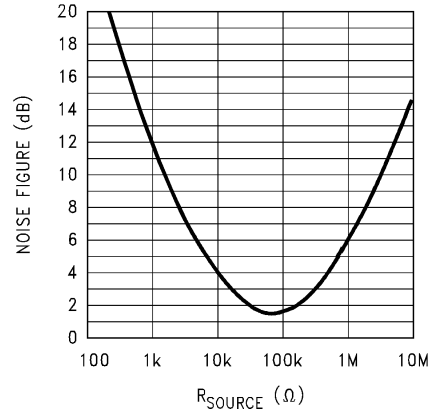


Figure 5-34. NF vs R_{Source}

5.10 Old Versus New Die Comparison

As of the publication of revision F of this data sheet, Texas Instruments has moved manufacturing of the die for LM6142 and LM6144 to a modern fabrication site. The two different die are referred to in this document as “old” (previous fabrication site) and “new” die. The die origin can be separated from the “Chip Source Origin” (CSO) parameter in the shipping information. The old die CSO is “GF6”, for the new die CSO is “RFB”. The old die information is maintained in this data sheet for comparison purposes, but all new manufacturing has moved to the new die.

Table 5-1. Old Versus New Die Comparison

Description	Old Die	New Die
Amsolute maximum supply voltage	35V	33V
Minimum supply voltage	1.8V	2.7V
Typical/Minimum output voltage range for 100kΩ load (V_S = 5V)	0.005V - 4.995V / 0.01V - 4.98V	0.045V - 4.97V / 0.05V - 4.96V
Typical output voltage range for 10kΩ load (V_S = 5V)	0.02V - 4.97V	0.05V - 4.96V
Output voltage slew architecture	Standard slew architecture	Slew-boosted architecture

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6 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

6.1 Application Information

The LM6142 brings a new level of ease of use to op amp system design.

With greater than rail-to-rail input voltage range concern over exceeding the common-mode voltage range is eliminated.

Rail-to-rail output swing provides the maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.

The high gain-bandwidth with low supply current opens new battery-powered applications, where high power consumption, previously reduced battery life to unacceptable levels.

To take advantage of these features, keep some ideas in mind.

6.2 Typical Applications

6.2.1 FISH FINDER/ DEPTH SOUNDER.

The LM6142/LM6144 is an excellent choice for battery operated fish finders. The low supply current, high gain-bandwidth and full rail to rail output swing of the LM6142 provides an ideal combination for use in this and similar applications.

6.2.2 ANALOG TO DIGITAL CONVERTER BUFFER

The high capacitive load driving ability, rail-to-rail input and output range with the excellent CMR of 82 dB, make the LM6142/LM6144 a good choice for buffering the inputs of A to D converters.

6.2.3 3 OP AMP INSTRUMENTATION AMP WITH RAIL-TO-RAIL INPUT AND OUTPUT

Using the LM6144, a 3 op amp instrumentation amplifier with rail-to-rail inputs and rail to rail output can be made. These features make these instrumentation amplifiers an excellent choice for single supply systems.

Some manufacturers use a precision voltage divider array of 5 resistors to divide the common-mode voltage to get an input range of rail-to-rail or greater. The problem with this method is that the method also divides the signal, so to even get unity gain, the amplifier must be run at high closed loop gains. This raises the noise and drift by the internal gain factor and lowers the input impedance. Any mismatch in these precision resistors reduces the CMR as well. Using the LM6144, all of these problems are eliminated.

In this example, amplifiers A and B act as buffers to the differential stage (Figure 6-1). These buffers maintain that the input impedance is over 100MΩ and the buffers eliminate the requirement for precision matched resistors in the input stage. The buffers also maintain that the difference amp is driven from a voltage source. This is necessary to maintain the CMR set by the matching of R1–R2 with R3–R4.

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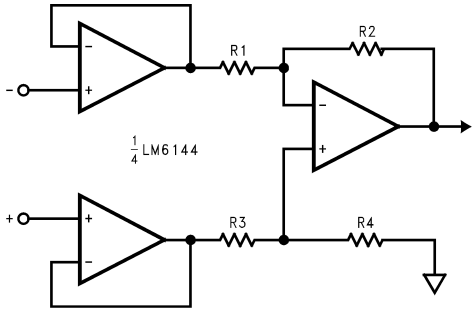


Figure 6-1.

The gain is set by the ratio of R2/R1 and R3 equals R1 and R4 equal R2. Making R4 slightly smaller than R2 and adding a trim pot equal to twice the difference between R2 and R4 allows the CMR to be adjusted for optimum.

With both rail to rail input and output ranges, the inputs and outputs are only limited by the supply voltages. Remember that even with rail-to-rail output, the output cannot swing past the supplies so the combined common mode voltage plus the signal must not be greater than the supplies or limiting occurs.

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7 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

7.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

7.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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All trademarks are the property of their respective owners.

7.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.4 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

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8 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (March 2013) to Revision E (May 2026)	Page
• Deleted "Swing 0.005V to 4.995V" in *Features*	1
• Deleted "Small Signal, 5V/µs" in *Features*	1
• Deleted "Large Signal, 30V/µs" in *Features*	1
• Changed Slew Rate to Slew Rate: 30V/µs in *Features*	1
• Changed supply range from 1.8V to 2.7V in *Features*	1
• Changed from "Operating on supplies of 1.8V" to "Operating on supplies of 2.7V"	1
• Updated table note 1 of *Absolute Maximum Ratings*	5
• Changed absolute maximum rating for supply voltage from 35V to 33V	5
• Deleted absolute maximum rating for current at power supply pin	5
• Updated table note 3 of *Absolute Maximum Ratings*	5
• Changed absolute maximum rating for input (common-mode) voltage from (V±) ± 0.3V to (V±) ± 0.5V	5
• Updated table note 4 of *Absolute Maximum Ratings*	5
• Changed absolute maximum rating for differential input voltage from 15V to ±15V	5
• Updated table note 2 of *Absolute Maximum Ratings*	5
• Changed absolute maximum rating for output current from ±25mA to Continuous	5
• Added absolute maximum rating for operating ambient temperature	5
• Deleted absolute maximum rating for lead temperature	5
• *Added ESD Ratings* table	5
• Changed HBM ESD rating from 2500V to ±4000V	5
• Changed minimum operating voltage from 1.8V to 2.7V	5
• Deleted table note 1 on Operating Ratings	5
• Added *Thermal Information* table for LM6142	6
• Changed junction-to-ambient thermal resistance for LM6142D from 193°C/w to 127.1°C/W	6
• Changed junction-to-ambient thermal resistance for LM6142P from 115°C/w to 84.45°C/W	6
• Added junction-to-case thermal resistance for LM6142	6
• Added junction-to-board thermal resistance for LM6142	6
• Added junction-to-top characterization parameter for LM6142	6
• Added junction-to-board characterization parameter for LM6142	6
• Added *Thermal Information* table for LM6144	6
• Changed junction-to-ambient thermal resistance for LM6144D from 126°C/W to 82.48°C/W	6
• Added junction-to-case (top) thermal resistance for LM6144	6
• Added junction-to-board thermal resistance for LM6144	6
• Added junction-to-top characterization parameter for LM6144	6
• Added junction-to-board characterization parameter for LM6144	6
• Updated all *Electrical Characteristics* tables to latest format	7
• Updated Output Swing format to refer to rails	7
• Changed typical voltage output swing for 100kΩ load from 4.995V to 30mV from positive rail	7
• Changed maximum voltage output swing for 100kΩ load from 4.98V to 40mV from positive rail	7
• Changed typical voltage output swing for 100kΩ load from 0.005V to 45mV from negative rail	7
• Changed maximum voltage output swing for 100kΩ load from 0.01V to 50mV from negative rail	7
• Changed maximum voltage output swing for 100kΩ load over temp range from 0.013V to 60mV from negative rail	7
• Changed typical voltage output swing for 10kΩ load from 4.97V to 40mV from positive rail	7
• Changed typical voltage output swing for 10kΩ load from 0.02V to 50mV from negative rail	7
• Deleted table notes for *Electrical Characteristics* tables	7
• Updated Output Swing format to refer to rails	9
• Changed maximum voltage output swing for 100kΩ load from 2.66V to 75mV from positive rail	9
• Updated Output Swing format to refer to rails	10

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- Added Open Loop Gain vs Load, for New Die....11
- Added CMRR and PSRR vs Frequency, for New Die.... 11
- Added a new sub-section *Old Versus New Die Comparison* 16
- Deleted sub-section *Enhanced Slew Rate* 17

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9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM6142AIMX/NOPB	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM614 2AIM
LM6142AIMX/NOPB.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM614 2AIM
LM6142AIMX/NOPB.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM614 2AIM
LM6142BIM/NOPB	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-40 to 85	LM614 2BIM
LM6142BIMX/NOPB	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM614 2BIM
LM6142BIMX/NOPB.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM614 2BIM
LM6142BIMX/NOPB.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM614 2BIM
LM6142BIN/NOPB	Active	Production	PDIP (P) | 8	40 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6142 BIN
LM6142BIN/NOPB.A	Active	Production	PDIP (P) | 8	40 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6142 BIN
LM6142BIN/NOPB.B	Active	Production	PDIP (P) | 8	40 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6142 BIN
LM6144AIM/NOPB	Obsolete	Production	SOIC (D) | 14	-	-	Call TI	Call TI	-40 to 85	LM6144 AIM
LM6144AIMX/NOPB	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM6144 AIM
LM6144AIMX/NOPB.A	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM6144 AIM
LM6144BIM/NOPB	Obsolete	Production	SOIC (D) | 14	-	-	Call TI	Call TI	-40 to 85	LM6144 BIM
LM6144BIMX/NOPB	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM6144 BIM
LM6144BIMX/NOPB.A	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM6144 BIM
LM6144BIN/NOPB	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6144BIN

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM6144BIN/NOPB.A	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6144BIN

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

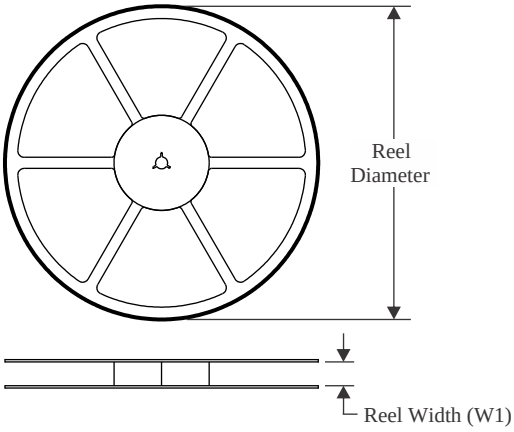
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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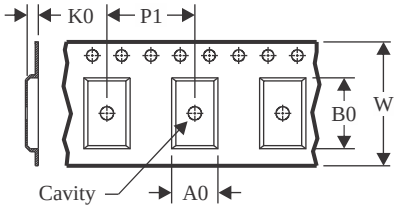
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

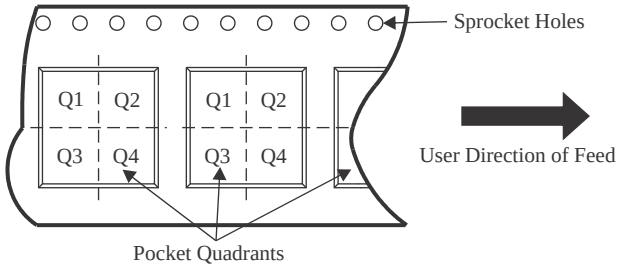


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

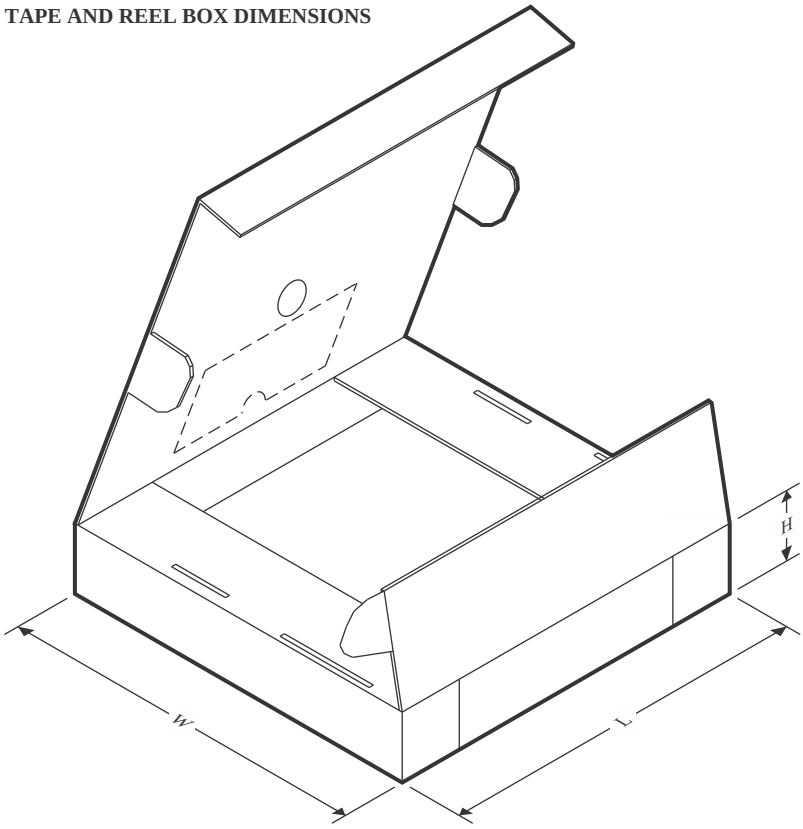
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM6142AIMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM6142BIMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM6144AIMX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LM6144BIMX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1

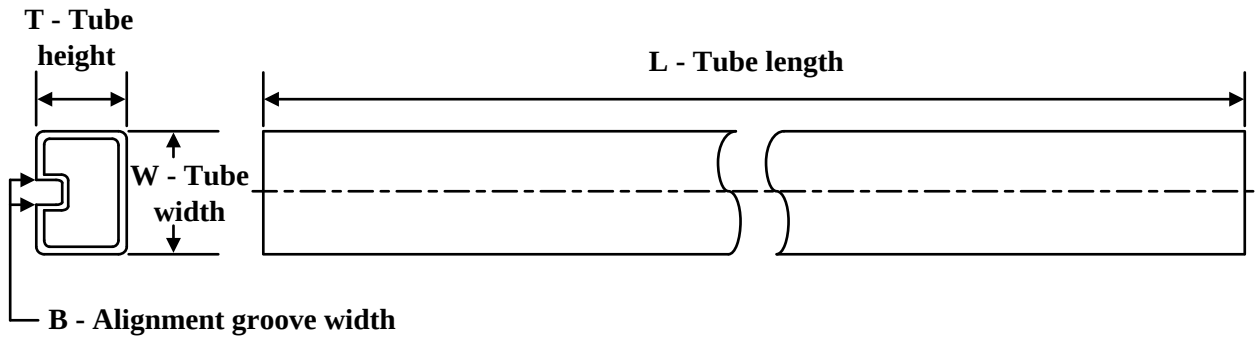
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

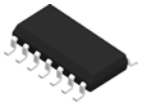
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM6142AIMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM6142BIMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM6144AIMX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0
LM6144BIMX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM6142BIN/NOPB	P	PDIP	8	40	502	14	11938	4.32
LM6142BIN/NOPB.A	P	PDIP	8	40	502	14	11938	4.32
LM6142BIN/NOPB.B	P	PDIP	8	40	502	14	11938	4.32
LM6144BIN/NOPB	N	PDIP	14	25	502	14	11938	4.32
LM6144BIN/NOPB.A	N	PDIP	14	25	502	14	11938	4.32

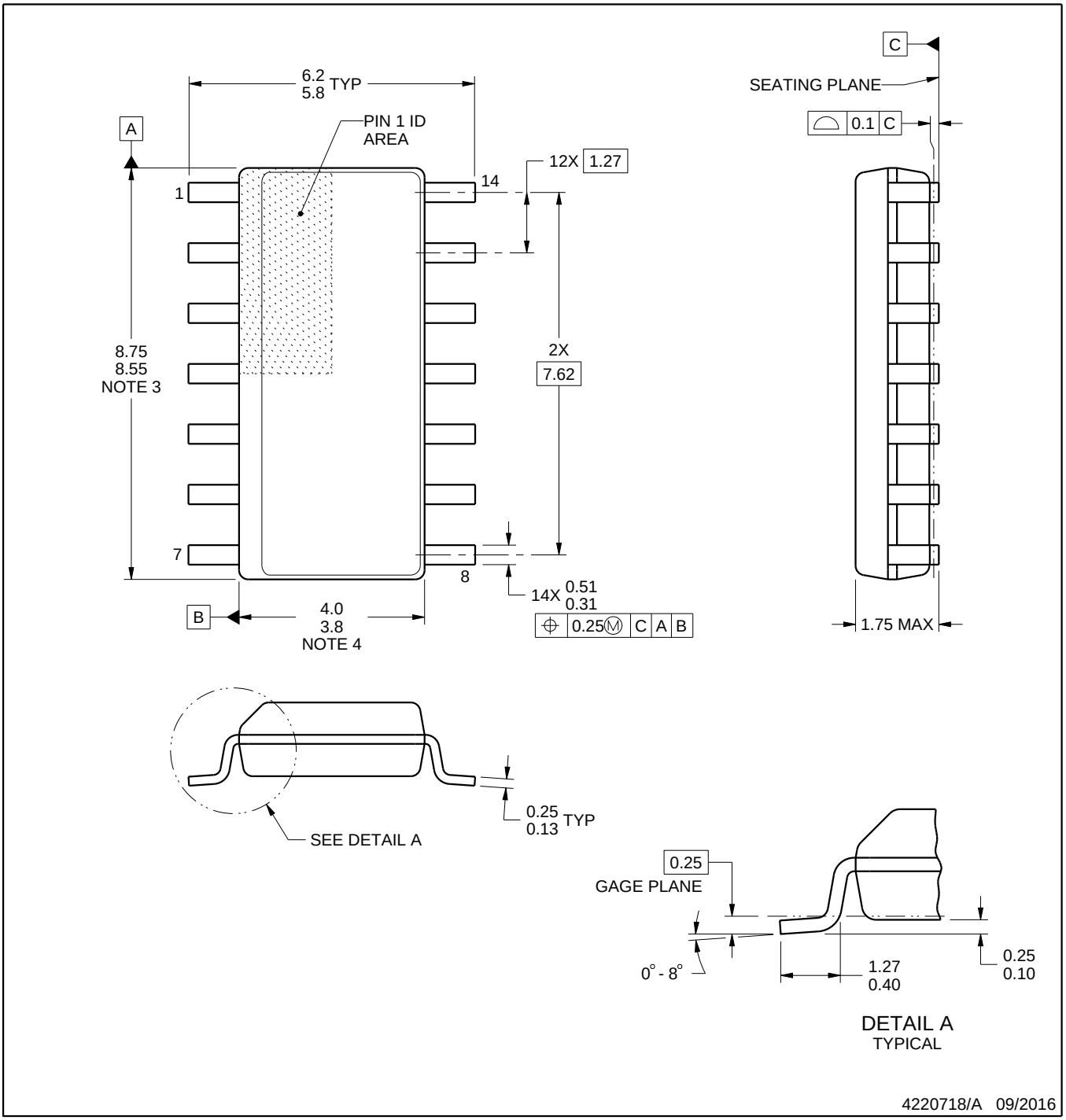


PACKAGE OUTLINE

D0014A

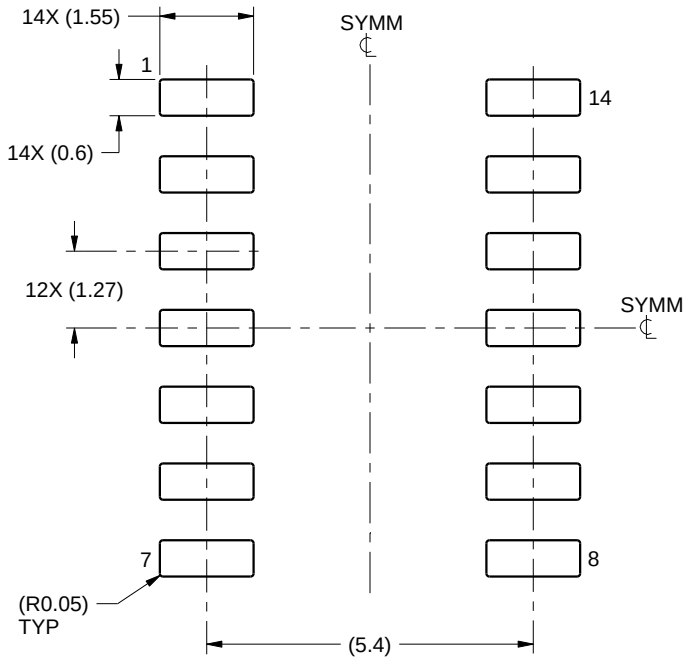
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

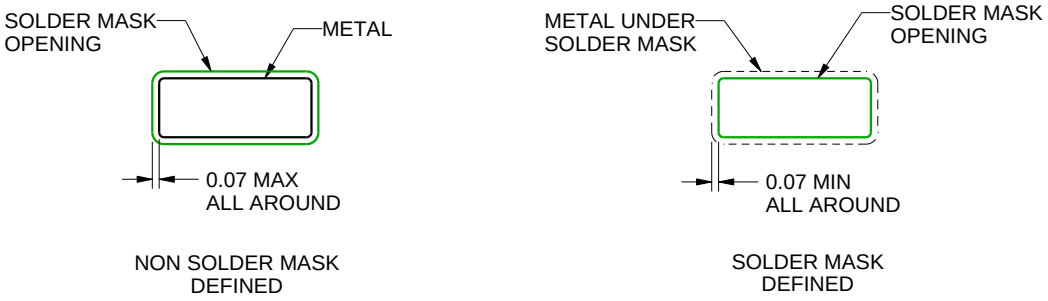


NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

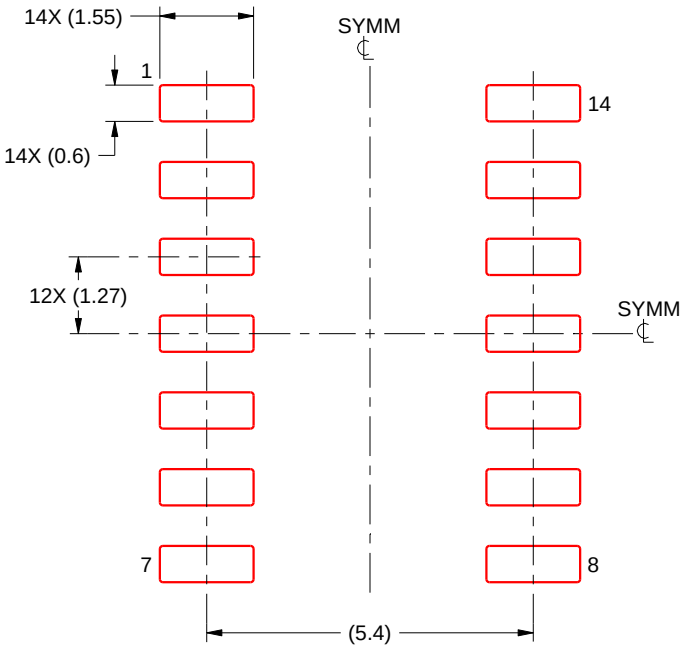
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

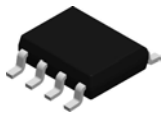


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

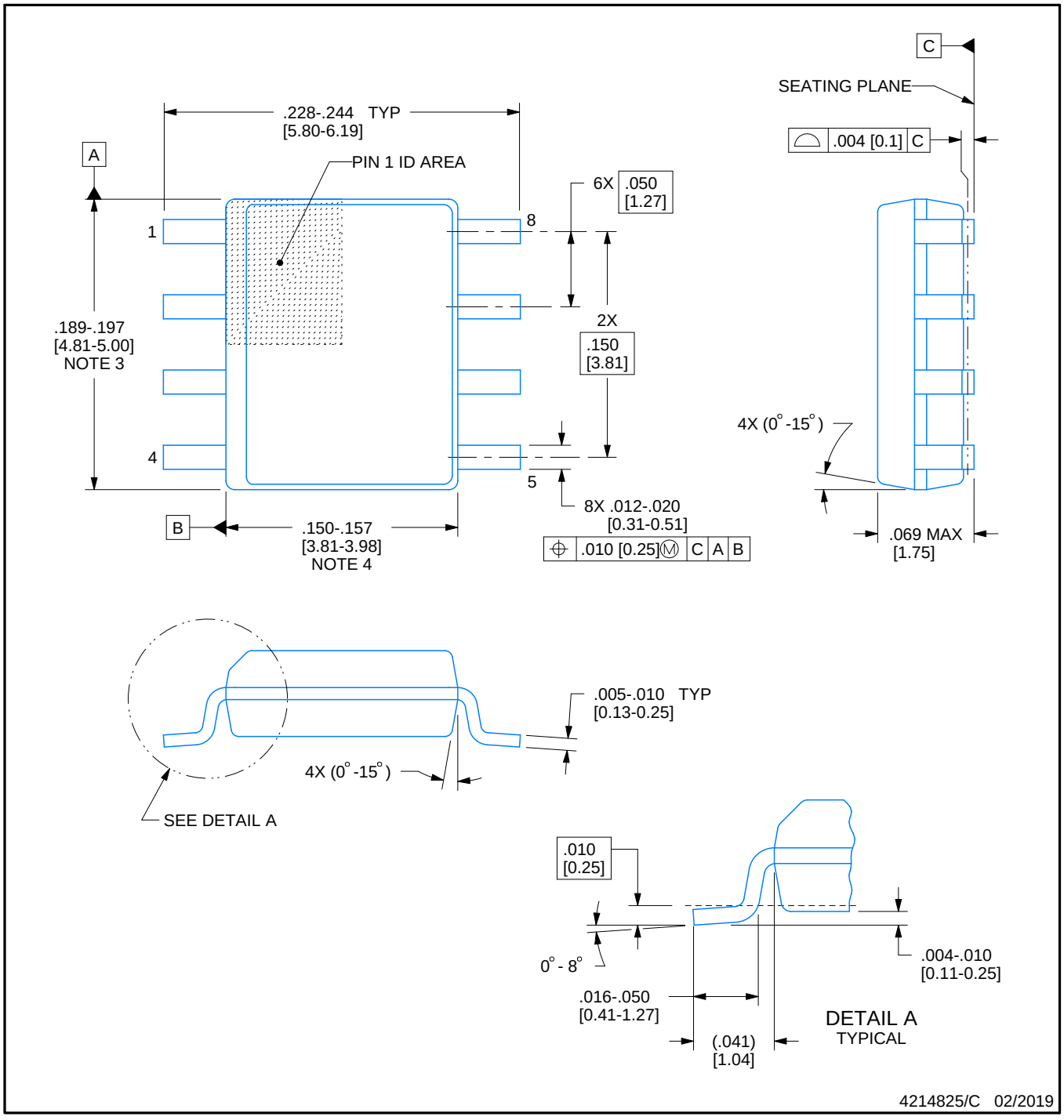


PACKAGE OUTLINE

D0008A

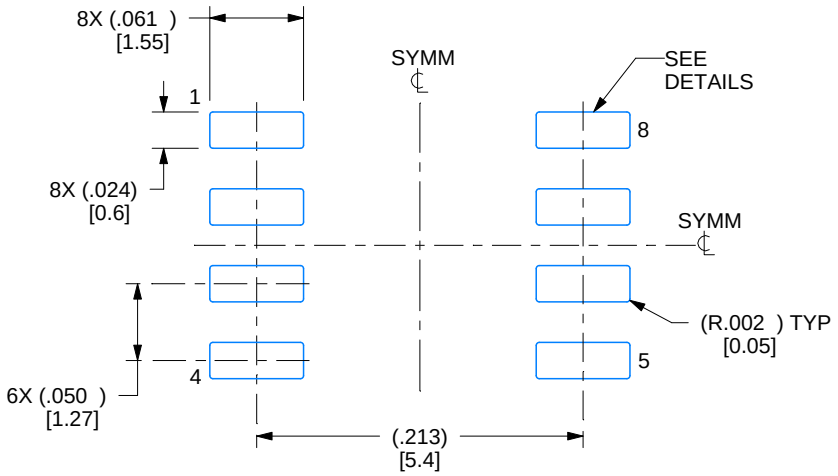
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

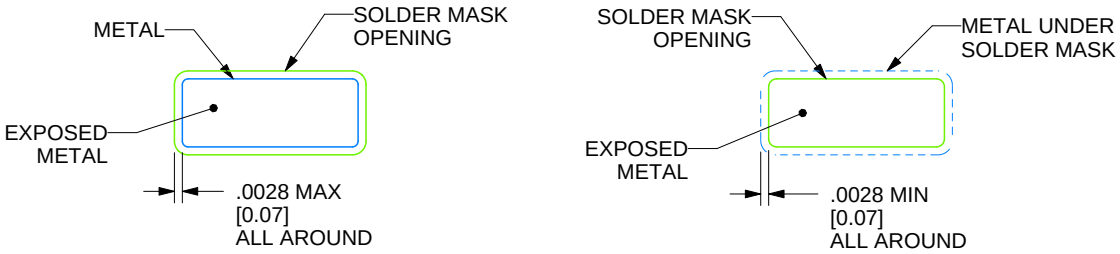


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

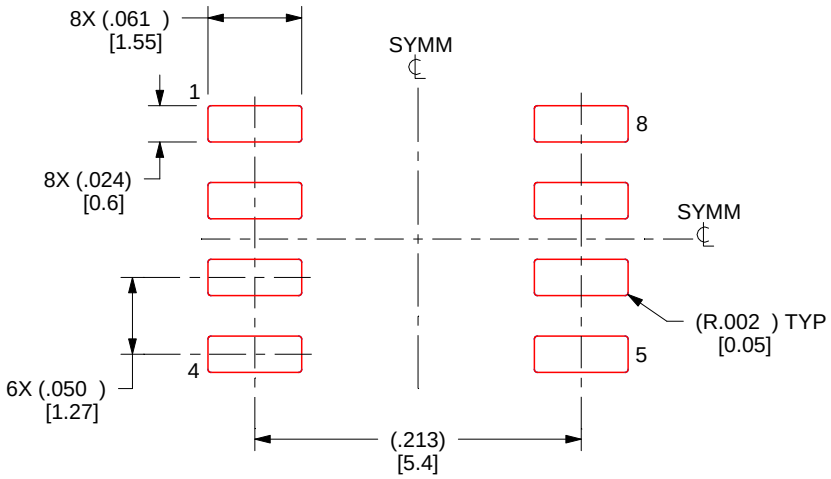
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



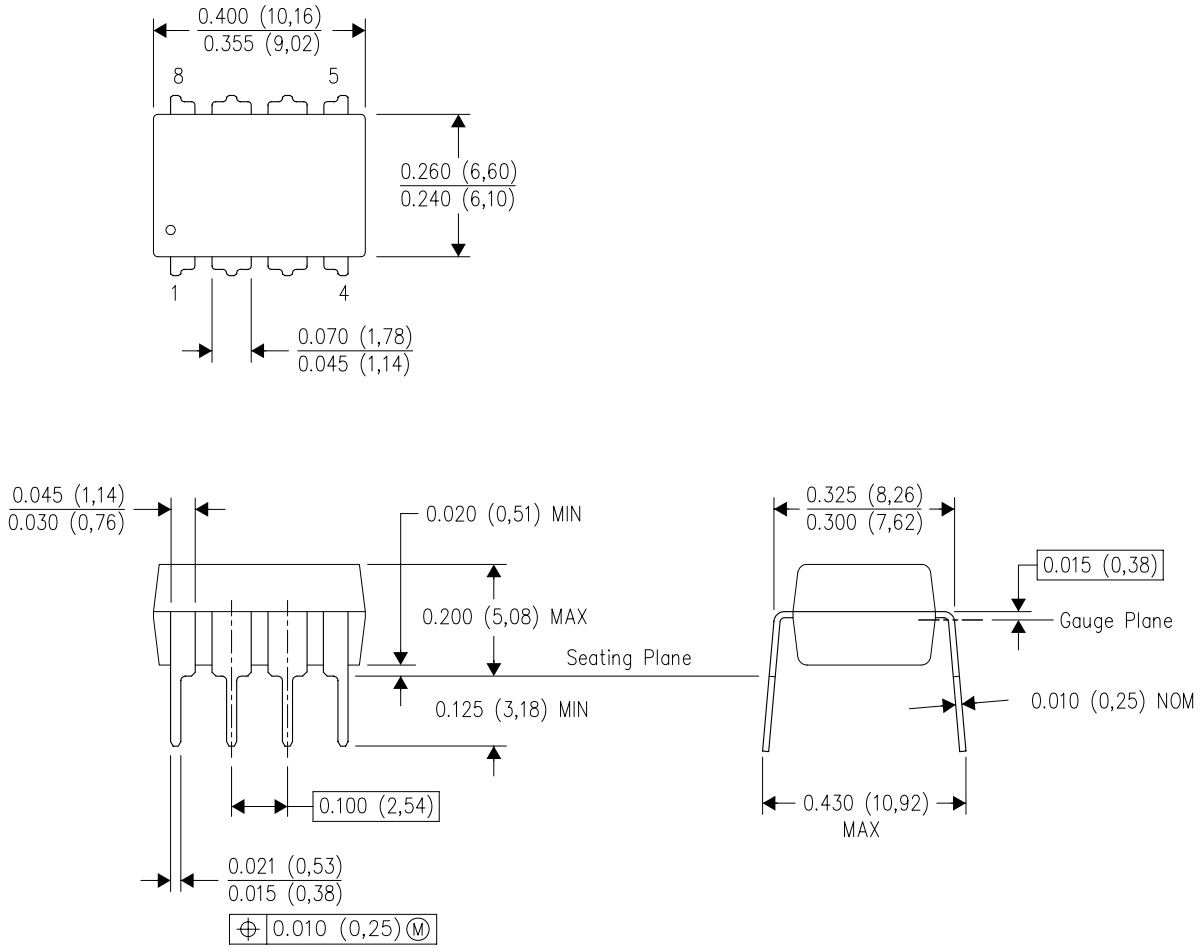
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE

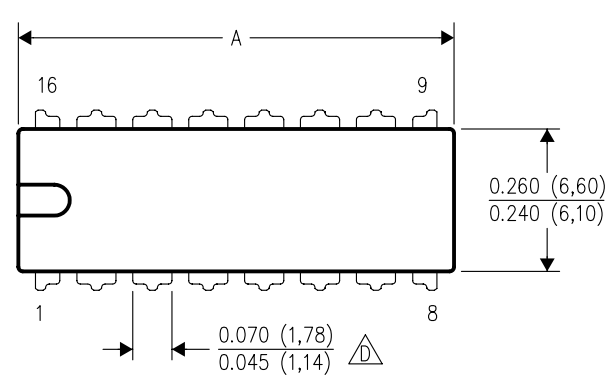


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

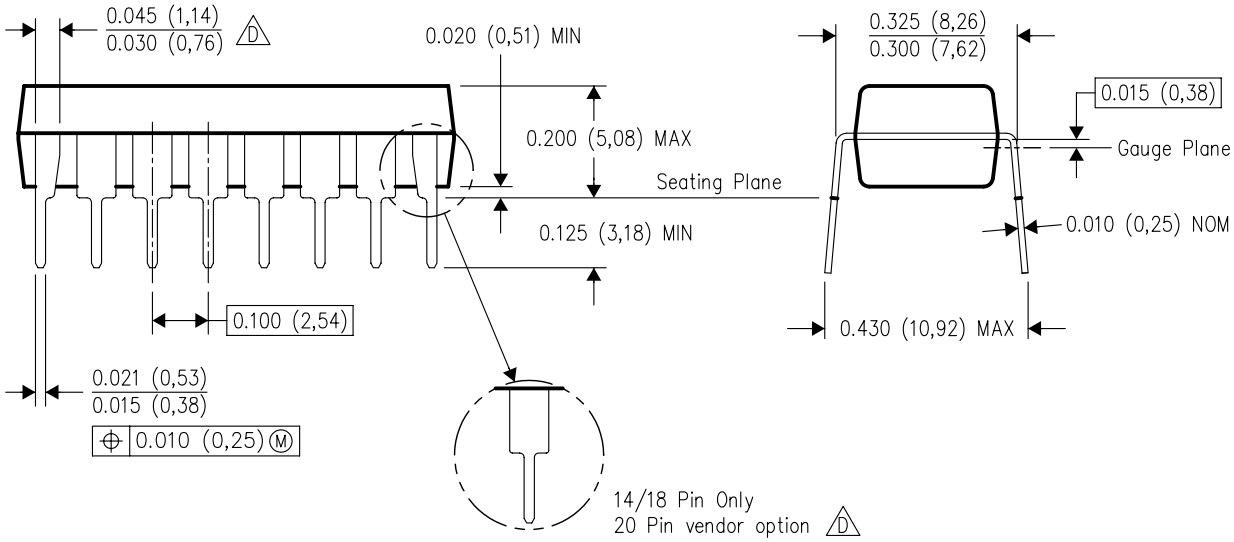
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

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